

Philips

Diode BYM36D

Datasheet

Silicon Diode

BYM36D

800V/2.9A

DATASHEET

OEM – Philips

Source: Philips Databook 1999

Fast soft-recovery controlled avalanche rectifiers

BYM36 series

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.

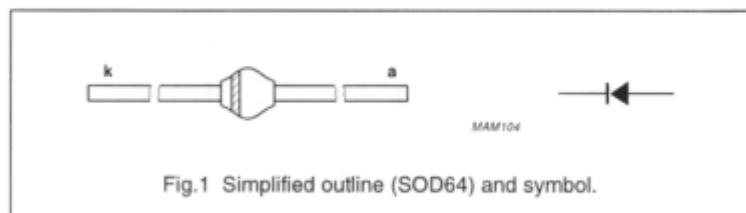


Fig.1 Simplified outline (SOD64) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage BYM36A		–	200	V
	BYM36B			400	V
	BYM36C			600	V
	BYM36D			800	V
	BYM36E			1000	V
	BYM36F			1200	V
	BYM36G			1400	V
V_R	continuous reverse voltage BYM36A		–	200	V
	BYM36B			400	V
	BYM36C			600	V
	BYM36D			800	V
	BYM36E			1000	V
	BYM36F			1200	V
	BYM36G			1400	V
$I_{F(AV)}$	average forward current BYM36A to C	$T_{tp} = 55^\circ\text{C}$; lead length = 10 mm; see Figs 2; 3 and 4 averaged over any 20 ms period; see also Figs 14; 15 and 16	–	3.0	A
	BYM36D and E			2.9	A
	BYM36F and G			2.9	A
	average forward current BYM36A to C			1.25	A
	BYM36D and E			1.20	A
	BYM36F and G			1.15	A

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SYMBOL	PARAMETER	CONDITIONS	RATE	MIN.	MAX.	UNIT
I _{FRM}	repetitive peak forward current BYM36A to C BYM36D and E BYM36F and G	T _{tp} = 55 °C; see Figs 8; 9 and 10	–	37	37	A
I _{FRM}	repetitive peak forward current BYM36A to C BYM36D and E BYM36F and G	T _{amb} = 65 °C; see Figs 11; 12 and 13	–	13	13	A
I _{FSM}	non-repetitive peak forward current	t = 10 ms half sine wave; T _j = T _{jmax} prior to surge; V _R = V _{RRMmax}	–	65	65	A
E _{RSM}	non-repetitive peak reverse avalanche energy	L = 120 mH; T _j = T _{jmax} prior to surge; inductive load switched off	–	10	10	mJ
T _{stg}	storage temperature		–65	+175	+175	°C
T _j	junction temperature	see Figs 17 and 18	–65	+175	+175	°C

ELECTRICAL CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage BYM36A to C BYM36D and E BYM36F and G	I _F = 3 A; T _j = T _{jmax} ; see Figs 19; 20 and 21	–	–	1.22	V
V _F	forward voltage BYM36A to C BYM36D and E BYM36F and G	I _F = 3 A; see Figs 19; 20 and 21	–	–	1.28	V
V _{(BR)R}	reverse avalanche breakdown voltage BYM36A BYM36B BYM36C BYM36D BYM36E BYM36F BYM36G	I _R = 0.1 mA	300	–	–	V
V _{(BR)R}			500	–	–	V
V _{(BR)R}			700	–	–	V
V _{(BR)R}			900	–	–	V
V _{(BR)R}			1100	–	–	V
V _{(BR)R}			1300	–	–	V
V _{(BR)R}			1500	–	–	V
I _R	reverse current	V _R = V _{RRMmax} ; see Fig.22	–	–	5	μA
I _R		V _R = V _{RRMmax} ; T _j = 165 °C; see Fig.22	–	–	150	μA

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t_{rr}	reverse recovery time BYM36A to C BYM36D and E BYM36F and G	when switched from $I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; measured at $I_R = 0.25 \text{ A}$; see Fig. 26	-	-	100	ns
C_d	diode capacitance BYM36A to C BYM36D and E BYM36F and G	$f = 1 \text{ MHz}$; $V_R = 0 \text{ V}$; see Figs 23 and 24	-	85	-	pF
$\left \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current BYM36A to C BYM36D and E BYM36F and G	when switched from $I_F = 1 \text{ A}$ to $V_R \geq 30 \text{ V}$ and $dI_F/dt = -1 \text{ A}/\mu\text{s}$; see Fig.27	-	-	7	A/ μ s
			-	-	6	A/ μ s
			-	-	5	A/ μ s

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th,j\text{-tp}}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th,j\text{-a}}$	thermal resistance from junction to ambient	note 1	75	K/W

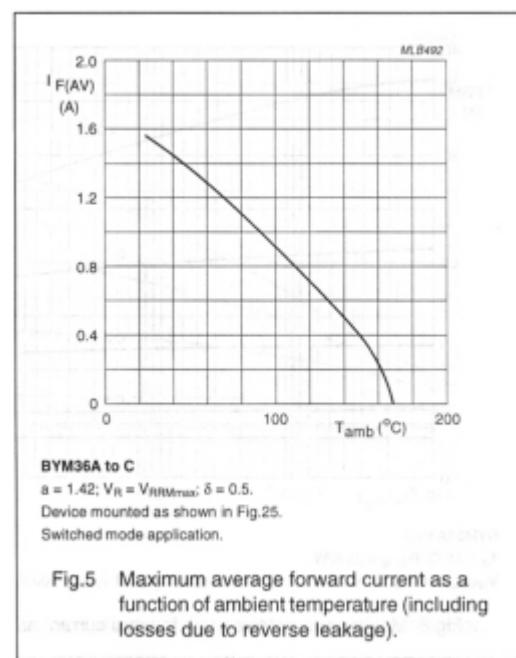
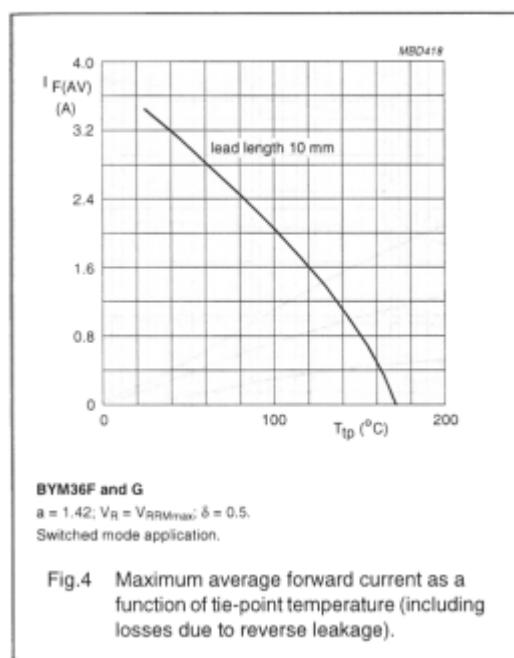
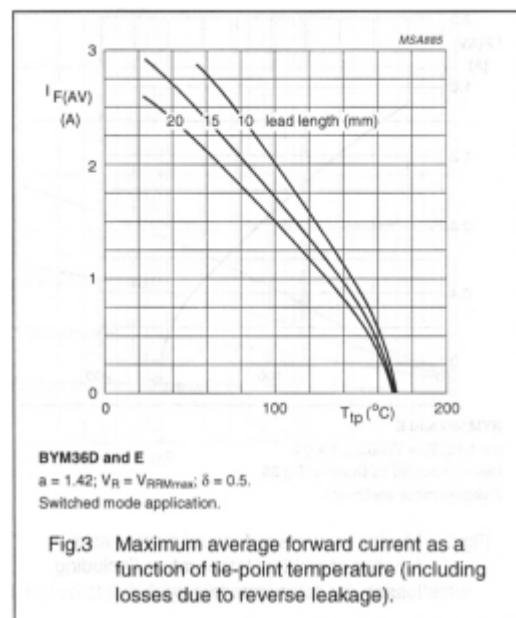
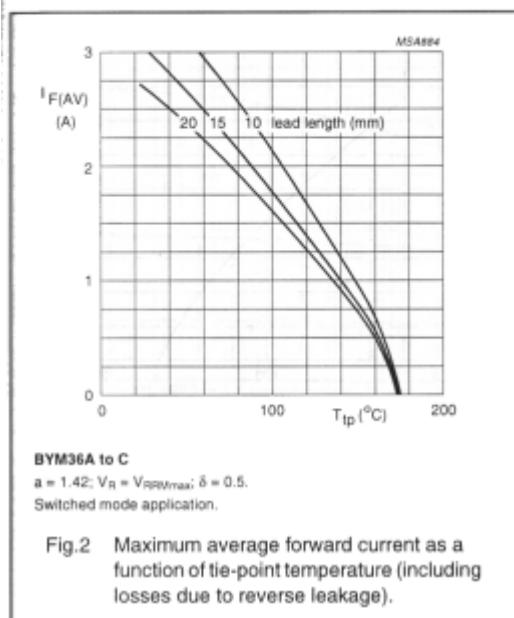
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer $\geq 40 \mu\text{m}$, see Fig.25.
For more information please refer to the 'General Part of Handbook SC01'.

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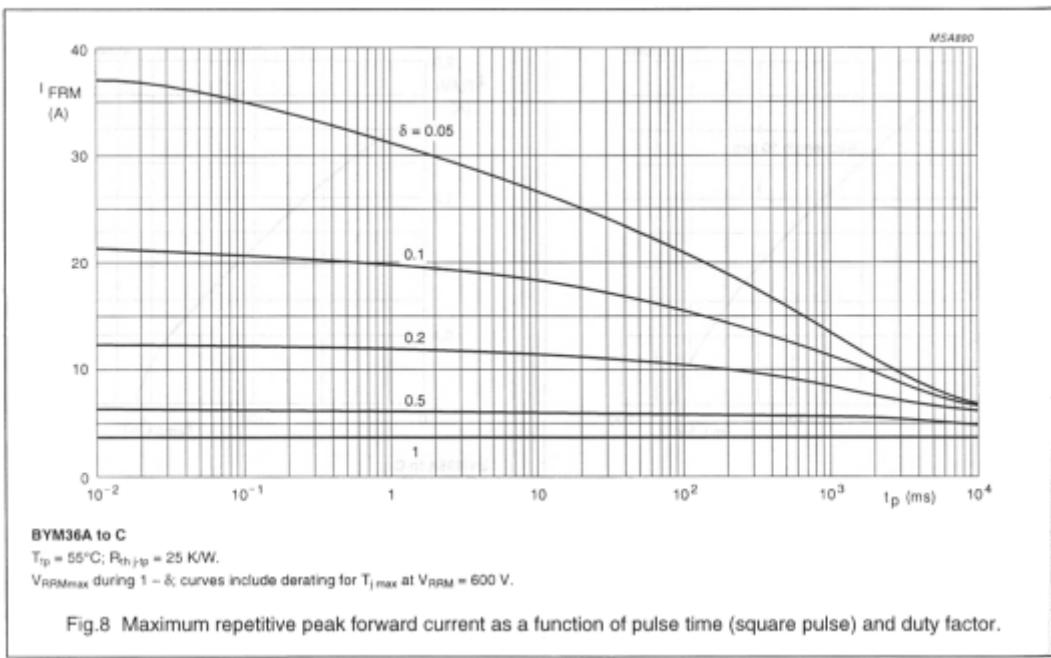
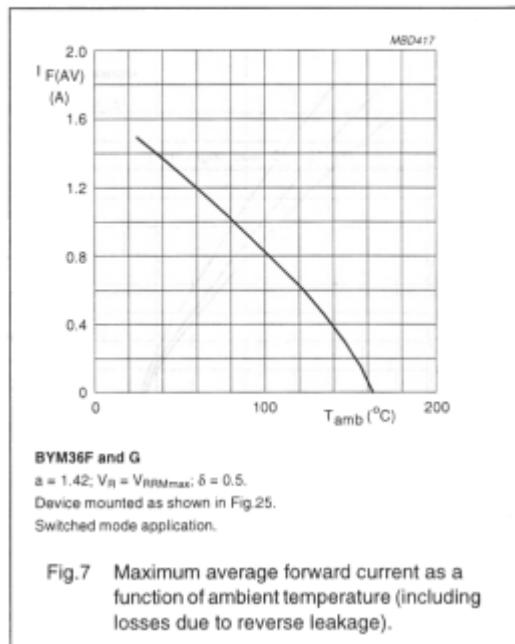
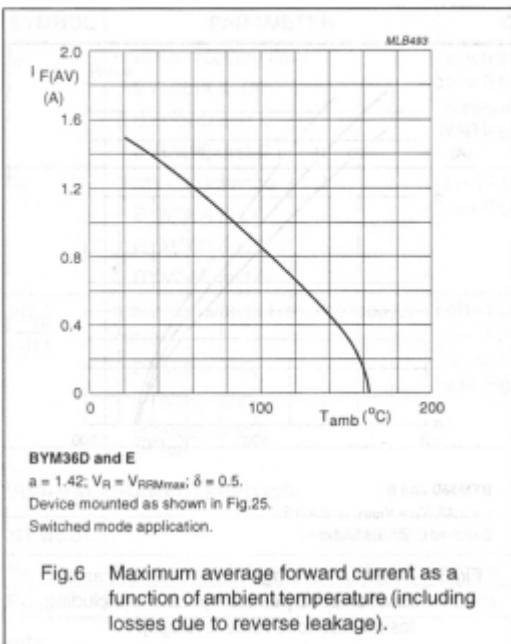
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GRAPHICAL DATA



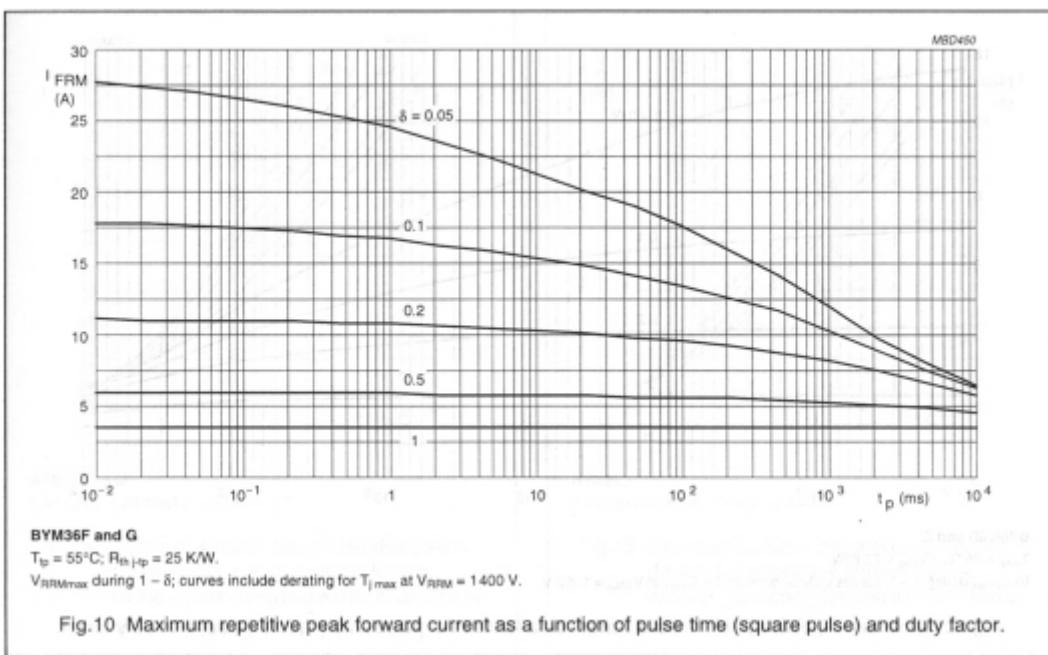
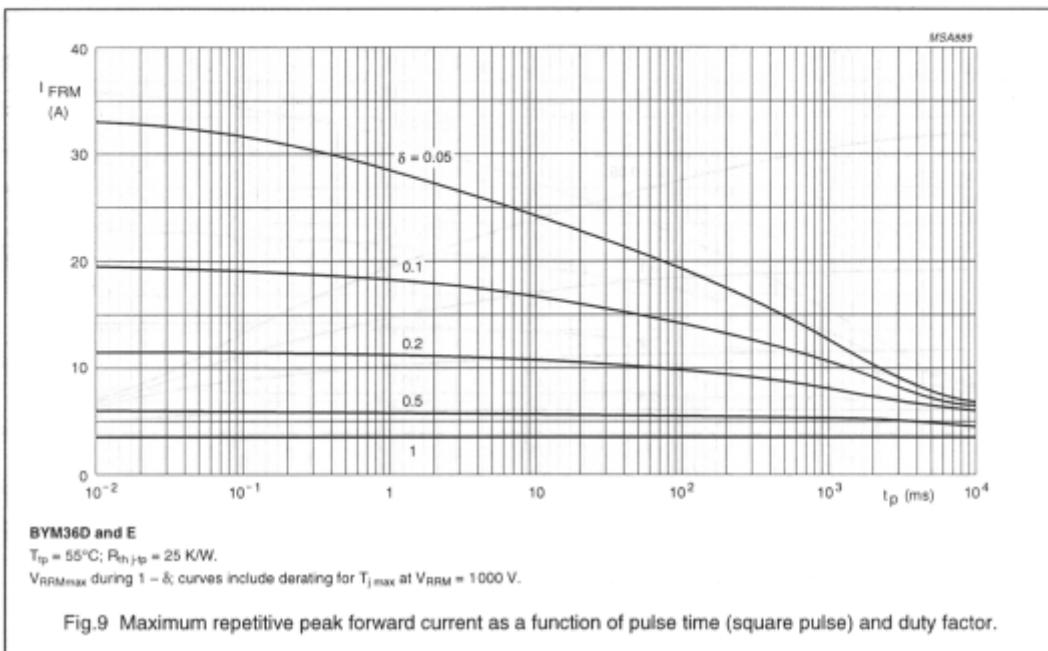
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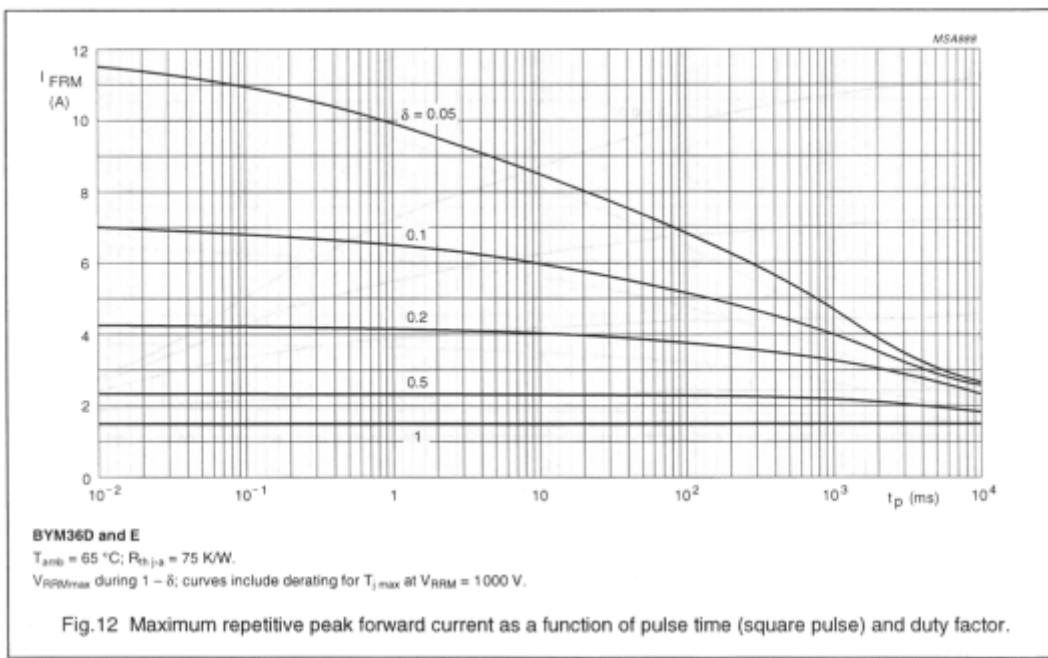
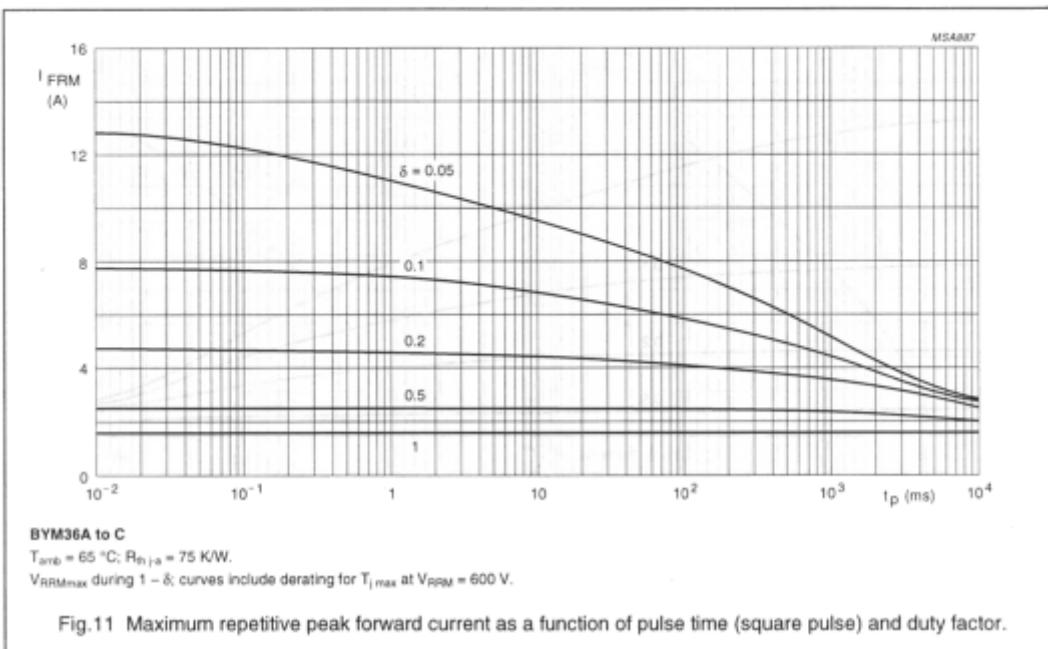
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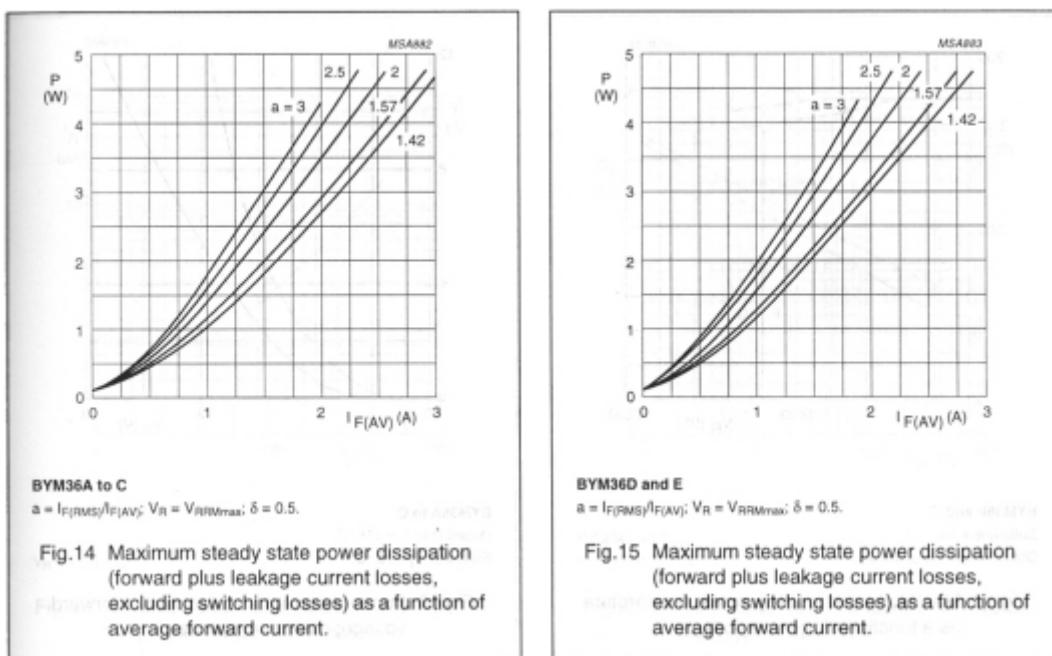
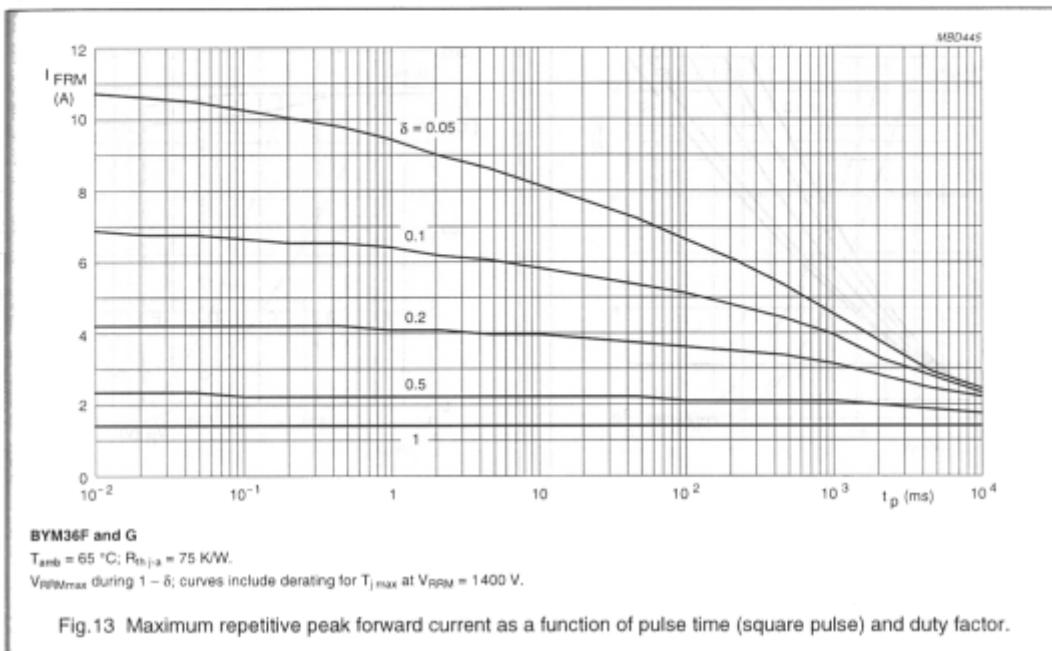
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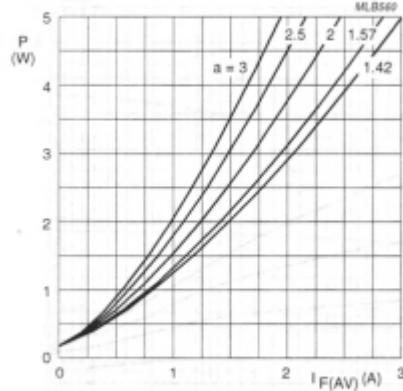
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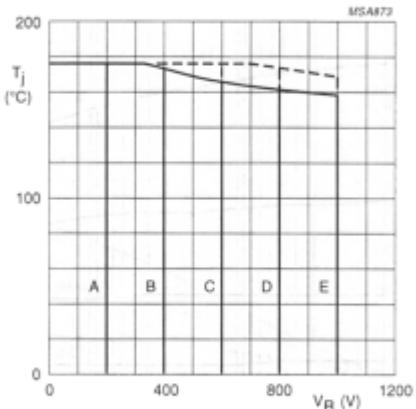
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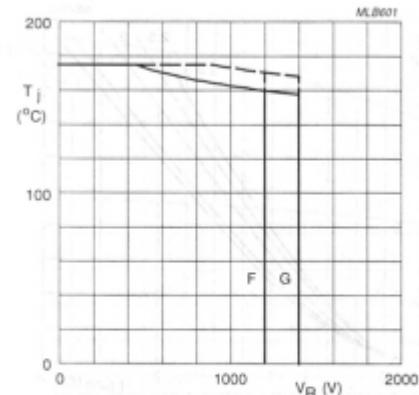
BYM36F and G
 $a = I_F(RMS)/I_F(AV); V_R = V_{RRMmax}; \delta = 0.5.$

Fig.16 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



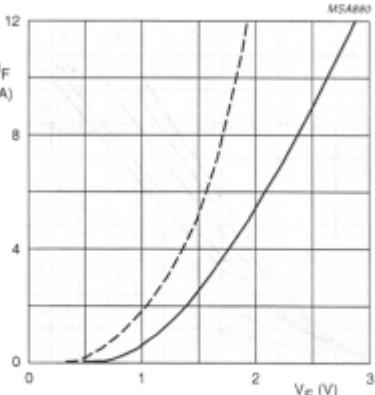
BYM36A to E
Solid line = V_R .
Dotted line = V_{RRM} ; $\delta = 0.5.$

Fig.17 Maximum permissible junction temperature as a function of reverse voltage.



BYM36F and G
Solid line = V_R .
Dotted line = V_{RRM} ; $\delta = 0.5.$

Fig.18 Maximum permissible junction temperature as a function of reverse voltage.

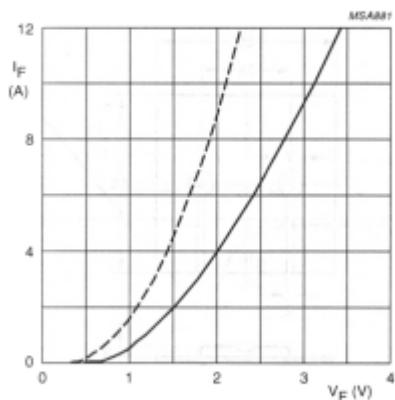


BYM36A to C
Dotted line: $T_j = 175$ °C.
Solid line: $T_j = 25$ °C.

Fig.19 Forward current as a function of forward voltage; maximum values.

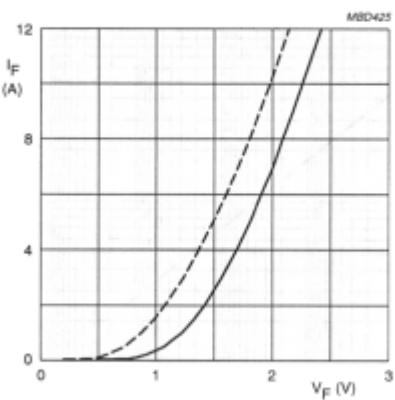
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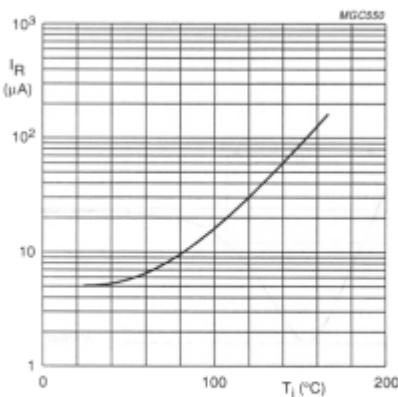
BYM36D and E.
Dotted line: $T_j = 175 \text{ }^\circ\text{C}$.
Solid line: $T_j = 25 \text{ }^\circ\text{C}$.

Fig.20 Forward current as a function of forward voltage; maximum values.



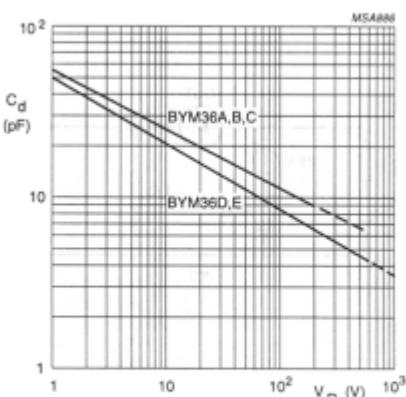
BYM36F and G.
Dotted line: $T_j = 175 \text{ }^\circ\text{C}$.
Solid line: $T_j = 25 \text{ }^\circ\text{C}$.

Fig.21 Forward current as a function of forward voltage; maximum values.



$V_R = V_{RRMmax}$.

Fig.22 Reverse current as a function of junction temperature; maximum values.

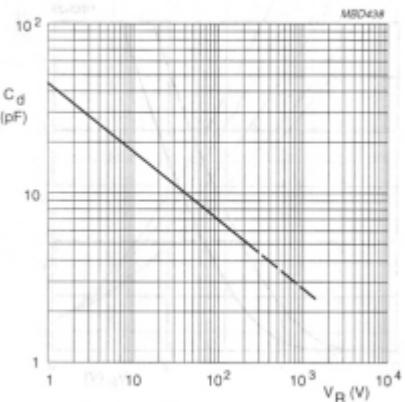


BYM36A to E
 $f = 1 \text{ MHz}; T_j = 25 \text{ }^\circ\text{C}$.

Fig.23 Diode capacitance as a function of reverse voltage, typical values.

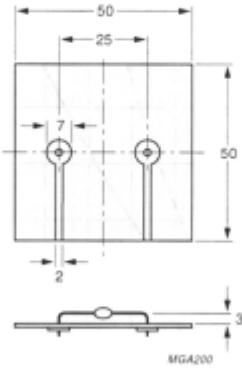
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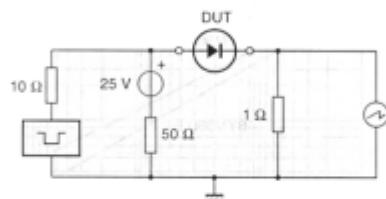
BYM36F and G
 $f = 1 \text{ MHz}$; $T_j = 25^\circ\text{C}$.

Fig.24 Diode capacitance as a function of reverse voltage, typical values.



Dimensions in mm.

Fig.25 Device mounted on a printed-circuit board.



Input impedance oscilloscope: $1 \text{ M}\Omega$, 22 pF ; $t_r \leq 7 \text{ ns}$.
Source impedance: 50Ω ; $t_r \leq 15 \text{ ns}$.

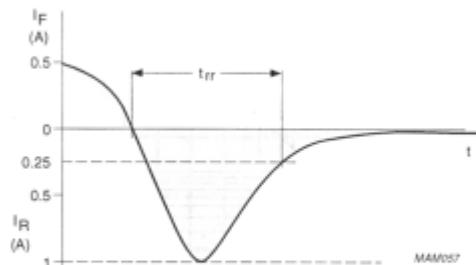


Fig.26 Test circuit and reverse recovery time waveform and definition.

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